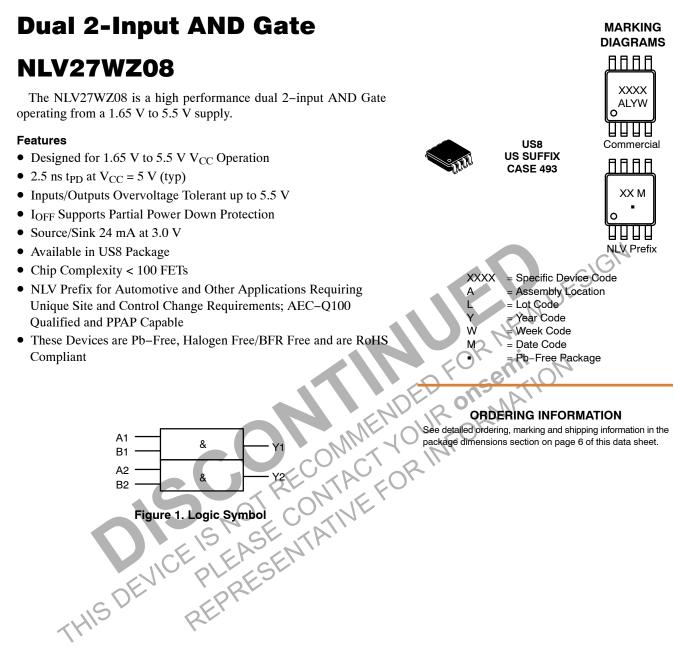
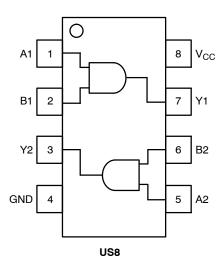
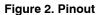
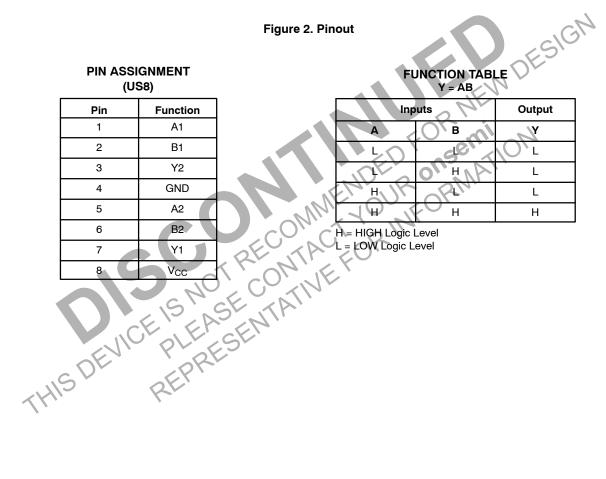
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## **NLV27WZ08**







#### MAXIMUM RATINGS

Symbol	Char	acteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		–0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		–0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
IOUT	DC Output Source/Sink Current		±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or	Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range		–65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case	for 10 secs	260	°C
TJ	Junction Temperature Under Bias		+150	∕ ∘C
$\theta_{JA}$	Thermal Resistance (Note 2)	US8	250	°C/W
PD	Power Dissipation in Still Air	US8	500	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
$V_{\text{ESD}}$	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		S ±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Applicable to devices with outputs that may be tri-stated.
Applicable to devices with outputs that may be tri-stated.
Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
Tested to FIA/JESD78 Close II

4. Tested to EIA/JESD78 Class II.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $\begin{array}{c} V_{CC}=1.65~V~to~1.95~V\\ V_{CC}=2.3~V~to~2.7~V\\ V_{CC}=3.0~V~to~3.6~V\\ V_{CC}=4.5~V~to~5.5~V \end{array}$	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## **NLV27WZ08**

#### DC ELECTRICAL CHARACTERISTICS

			Vcc	T <sub>A</sub> = 25°C		–55°C ≤ T	A ≤ 125°C		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Мах	Units
VIH	High-Level Input		1.65 to 1.95	0.75 x V <sub>CC</sub>			$0.75  ext{ x V}_{CC}$		V
	Voltage		2.3 to 5.5	$0.70 \times V_{CC}$			$0.70 \times V_{CC}$		
V <sub>IL</sub>	Low-Level Input		1.65 to 1.95			0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>	V
	Voltage		2.3 to 5.5			0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>	
V <sub>OH</sub>	High-Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ I_{OH} = -100 \ \mu A \\ I_{OH} = -4 \ m A \\ I_{OH} = -8 \ m A \\ I_{OH} = -12 \ m A \\ I_{OH} = -16 \ m A \\ I_{OH} = -24 \ m A \\ I_{OH} = -32 \ m A \end{array} $	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	$\begin{array}{c} V_{CC} = 0.1 \\ 1.29 \\ 1.9 \\ 2.2 \\ 2.4 \\ 2.3 \\ 3.8 \end{array}$	V <sub>CC</sub> 1.4 2.1 2.4 2.7 2.5 4.0		V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8		V
V <sub>OL</sub>	Low-Level Output Voltage	$ \begin{array}{l} V_{ N} = V_{ H} \mbox{ or } V_{ L} \\ I_{OL} = 100 \ \mu A \\ I_{OL} = 4 \ m A \\ I_{OL} = 8 \ m A \\ I_{OL} = 12 \ m A \\ I_{OL} = 16 \ m A \\ I_{OL} = 24 \ m A \\ I_{OL} = 32 \ m A \end{array} $	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55	- - - - - - - - - - - - - - - - - - -	0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I <sub>IN</sub>	Input Leakage Current	$V_{IN}$ = 5.5 V or GND	1.65 to 5.5	-		0.1	-	±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	JF'	1.0	"ION	10	μA
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5	NDE	2	1.0	- \	10	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

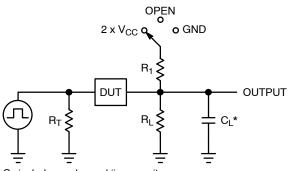
### AC ELECTRICAL CHARACTERISTICS

				٦	Γ <sub>A</sub> = 25°C	2	T <sub>A</sub> = -55	to 125°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Test Conditions	Min	Тур	Max	Min	Max	Units
t <sub>PLH</sub> ,	Propagation Delay,	1.65 to 1.95	$C_L = 15  pF$	-	5.7	10.5	-	11.0	ns
<sup>t</sup> PHL	(A or B) to Y	2.3 to 2.7	R <sub>L</sub> = 1 MΩ R <sub>1</sub> = Open	-	3.5	5.8	-	6.2	
		3.0 to 3.6		-	2.6	3.9	-	4.3	
		4.5 to 5.5		-	1.9	3.1	-	3.3	
		3.0 to 3.6	$C_{L} = 50 \text{ pF},$	-	3.2	4.8	-	5.2	
		4.5 to 5.5	$R_L = 500 \Omega$ , $R_1 = Open$	_	2.5	3.7	-	4.0	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter Condition		Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub> 10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	9 11	pF

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

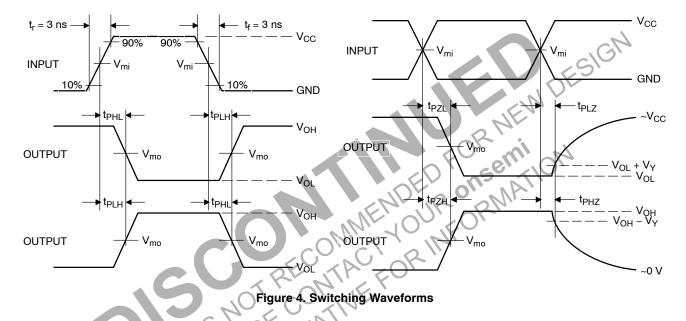


Test	Switch Position	C <sub>L</sub> , pF	$R_{L}, \Omega$	<b>R</b> <sub>1</sub> , Ω	
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table			
t <sub>PLZ</sub> / t <sub>PZL</sub>	$2 \times V_{CC}$	50	500	500	
$t_{PHZ}$ / $t_{PZH}$	GND	50	500	500	
V Den't Car					

X = Don't Care

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

## Figure 3. Test Circuit



	NCENERGE	Vm	<sub>o</sub> , V	
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>Y</sub> , V
1.65 to 1.95	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
2.3 to 2.7	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

## **NLV27WZ08**

#### **DEVICE ORDERING INFORMATION**

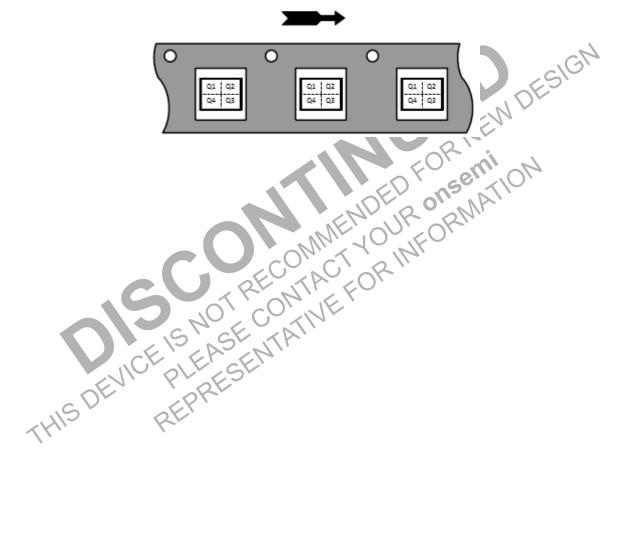
Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NLV27WZ08USG*	US8	L2	Q4	3000 / Tape & Reel
NL27WZ08USG-L22190	US8	L2	Q4	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

#### Pin 1 Orientation in Tape and Reel

## Direction of Feed

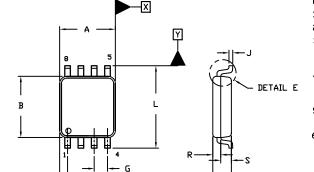


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SCALE 4:1



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DETAIL E

NOTES:

US8 **CASE 493 ISSUE F** 

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: MILLIMETERS

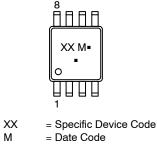
R 0.10 TYP

- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSION, З. OR GATE BURR. MOLD FLASH, PROTRUSION, OR GATE BURR SHALL NOT EXCEED 0.14 (0.0055') PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT 4. EXCEED 0.14 (0.0055") PER SIDE.
- LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 5. 0.0076-0.0203 MM (0.003-0.008").

ALL TELERANCE UNLESS ETHERWISE SPECIFIED ±0.0508 MM (0.002"). 6.

	MILLIMETERS		INC	HES
DIM	MIN.	MAX.	MIN.	MAX.
A	1.90	2.10	0.075	0.083
B	2.20	2.40	0.087	0.094
С	0.60	0.90	0.024	0.035
D	0.17	0.25	0.007	0.010
F	0.20	0.35	0.008	0.014
G	0.50	BSC	0.020	BSC
н	0.40	REF	0.016	REF
J	0.10	0.18	0.004	0.007
к	0.00	0.10	0.000	0.004
L	3.00	3.25	0.118	0.128
м	0*	6*	0*	6*
N	0*	10*	0*	10*
Р	0.23	0.34	0.010	0.013
R	0.23	0.33	0.009	0.013
S	0.37	0.47	0.015	0.019
U	0.60	0.80	0.024	0.031
V	0.12	BSC	0.005	BSC

#### GENERIC **MARKING DIAGRAM\***



= Pb-Free Package

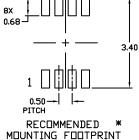
(Note: Microdot may be in either location)

Μ

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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P -c 0.10 (0.004) T SEATING PLANE n 甶 ⊕0.10 (0.004) ₩ T X Y 8X 0.30-8X



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